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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Active
Core Processor	ARM® Cortex®-A9
Number of Cores/Bus Width	4 Core, 32-Bit
Speed	852MHz
Co-Processors/DSP	Multimedia; NEON™ SIMD
RAM Controllers	LPDDR2, LVDDR3, DDR3
Graphics Acceleration	Yes
Display & Interface Controllers	Keypad, LCD
Ethernet	10/100/1000Mbps (1)
SATA	SATA 3Gbps (1)
USB	USB 2.0 + PHY (4)
Voltage - I/O	1.8V, 2.5V, 2.8V, 3.3V
Operating Temperature	-40°C ~ 125°C (TJ)
Security Features	ARM TZ, Boot Security, Cryptography, RTIC, Secure Fusebox, Secure JTAG, Secure Memory, Secure RTC, Tamper Detection
Package / Case	624-FBGA, FCBGA
Supplier Device Package	624-FCBGA (21x21)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcimx6q4avt08ae

  - 1-bit or 4-bit transfer mode specifications for SD and SDIO cards up to UHS-I SDR-104 mode (104 MB/s max)
  - 1-bit, 4-bit, or 8-bit transfer mode specifications for MMC cards up to 52 MHz in both SDR and DDR modes (104 MB/s max)
- USB:
  - One High Speed (HS) USB 2.0 OTG (Up to 480 Mbps), with integrated HS USB PHY
  - Three USB 2.0 (480 Mbps) hosts:
    - One HS host with integrated High Speed PHY
    - Two HS hosts with integrated High Speed Inter-Chip (HS-IC) USB PHY
- Expansion PCI Express port (PCIe) v2.0 one lane
  - PCI Express (Gen 2.0) dual mode complex, supporting Root complex operations and Endpoint operations. Uses x1 PHY configuration.
- Miscellaneous IPs and interfaces:
  - SSI block capable of supporting audio sample frequencies up to 192 kHz stereo inputs and outputs with I^2S mode
  - ESAI is capable of supporting audio sample frequencies up to 260 kHz in I2S mode with 7.1 multi channel outputs
  - Five UARTs, up to 5.0 Mbps each:
    - Providing RS232 interface
    - Supporting 9-bit RS485 multidrop mode
    - One of the five UARTs (UART1) supports 8-wire while the other four support 4-wire. This is due to the SoC IOMUX limitation, because all UART IPs are identical.
  - Five eCSPI (Enhanced CSPI)
  - Three I2C, supporting 400 kbps
  - Gigabit Ethernet Controller (IEEE1588 compliant), 10/100/1000[1] Mbps
  - Four Pulse Width Modulators (PWM)
  - System JTAG Controller (SJC)
  - GPIO with interrupt capabilities
  - 8x8 Key Pad Port (KPP)
  - Sony Philips Digital Interconnect Format (SPDIF), Rx and Tx
  - Two Controller Area Network (FlexCAN), 1 Mbps each
  - Two Watchdog timers (WDOG)
  - Audio MUX (AUDMUX)
  - MLB (MediaLB) provides interface to MOST Networks (150 Mbps) with the option of DTCP cipher accelerator

1. The theoretical maximum performance of 1 Gbps ENET is limited to 470 Mbps (total for Tx and Rx) due to internal bus throughput limitations. The actual measured performance in optimized environment is up to 400 Mbps. For details, see the ERR004512 erratum in the i.MX 6Dual/6Quad errata document (IMX6DQCE).

Table 2. i.MX 6Dual/6Quad Modules List (continued)

Block Mnemonic	Block Name	Subsystem	Brief Description
EPIT-1 EPIT-2	Enhanced Periodic Interrupt Timer	Timer Peripherals	Each EPIT is a 32-bit “set and forget” timer that starts counting after the EPIT is enabled by software. It is capable of providing precise interrupts at regular intervals with minimal processor intervention. It has a 12-bit prescaler for division of input clock frequency to get the required time setting for the interrupts to occur, and counter value can be programmed on the fly.
ESAI	Enhanced Serial Audio Interface	Connectivity Peripherals	The Enhanced Serial Audio Interface (ESAI) provides a full-duplex serial port for serial communication with a variety of serial devices, including industry-standard codecs, SPDIF transceivers, and other processors. The ESAI consists of independent transmitter and receiver sections, each section with its own clock generator. All serial transfers are synchronized to a clock. Additional synchronization signals are used to delineate the word frames. The normal mode of operation is used to transfer data at a periodic rate, one word per period. The network mode is also intended for periodic transfers; however, it supports up to 32 words (time slots) per period. This mode can be used to build time division multiplexed (TDM) networks. In contrast, the on-demand mode is intended for non-periodic transfers of data and to transfer data serially at high speed when the data becomes available. The ESAI has 12 pins for data and clocking connection to external devices.
FlexCAN-1 FlexCAN-2	Flexible Controller Area Network	Connectivity Peripherals	The CAN protocol was primarily, but not only, designed to be used as a vehicle serial data bus, meeting the specific requirements of this field: real-time processing, reliable operation in the Electromagnetic interference (EMI) environment of a vehicle, cost-effectiveness and required bandwidth. The FlexCAN module is a full implementation of the CAN protocol specification, Version 2.0 B, which supports both standard and extended message frames.
GPIO-1 GPIO-2 GPIO-3 GPIO-4 GPIO-5 GPIO-6 GPIO-7	General Purpose I/O Modules	System Control Peripherals	Used for general purpose input/output to external devices. Each GPIO module supports 32 bits of I/O.
GPMI	General Purpose Media Interface	Connectivity Peripherals	The GPMI module supports up to 8x NAND devices. 40-bit ECC error correction for NAND Flash controller (GPMI2). The GPMI supports separate DMA channels per NAND device.
GPT	General Purpose Timer	Timer Peripherals	Each GPT is a 32-bit “free-running” or “set and forget” mode timer with programmable prescaler and compare and capture register. A timer counter value can be captured using an external event and can be configured to trigger a capture event on either the leading or trailing edges of an input pulse. When the timer is configured to operate in “set and forget” mode, it is capable of providing precise interrupts at regular intervals with minimal processor intervention. The counter has output compare logic to provide the status and interrupt at comparison. This timer can be configured to run either on an external clock or on an internal clock.

Table 2. i.MX 6Dual/6Quad Modules List (continued)

Block Mnemonic	Block Name	Subsystem	Brief Description
uSDHC-1 uSDHC-2 uSDHC-2 uSDHC-4	SD/MMC and SDXC Enhanced Multi-Media Card / Secure Digital Host Controller	Connectivity Peripherals	i.MX 6Dual/6Quad specific SoC characteristics: All four MMC/SD/SDIO controller IPs are identical and are based on the uSDHC IP. They are: • Conforms to the SD Host Controller Standard Specification version 3.0 • Fully compliant with MMC command/response sets and Physical Layer as defined in the Multimedia Card System Specification, v4.2/4.3/4.4/4.41 including high-capacity (size > 2 GB) cards HC MMC. Hardware reset as specified for eMMC cards is supported at ports #3 and #4 only. • Fully compliant with SD command/response sets and Physical Layer as defined in the SD Memory Card Specifications, v3.0 including high-capacity SDHC cards up to 32 GB and SDXC cards up to 2TB. • Fully compliant with SDIO command/response sets and interrupt/read-wait mode as defined in the SDIO Card Specification, Part E1, v1.10 • Fully compliant with SD Card Specification, Part A2, SD Host Controller Standard Specification, v2.00 All four ports support: • 1-bit or 4-bit transfer mode specifications for SD and SDIO cards up to UHS-I SDR104 mode (104 MB/s max) • 1-bit, 4-bit, or 8-bit transfer mode specifications for MMC cards up to 52 MHz in both SDR and DDR modes (104 MB/s max) However, the SoC-level integration and I/O muxing logic restrict the functionality to the following: • Instances #1 and #2 are primarily intended to serve as external slots or interfaces to on-board SDIO devices. These ports are equipped with “Card Detection” and “Write Protection” pads and do not support hardware reset. • Instances #3 and #4 are primarily intended to serve interfaces to embedded MMC memory or interfaces to on-board SDIO devices. These ports do not have “Card detection” and “Write Protection” pads and do support hardware reset. • All ports can work with 1.8 V and 3.3 V cards. There are two completely independent I/O power domains for Ports #1 and #2 in four bit configuration (SD interface). Port #3 is placed in his own independent power domain and port #4 shares power domain with some other interfaces.
VDOA	VDOA	Multimedia Peripherals	The Video Data Order Adapter (VDOA) is used to re-order video data from the “tiled” order used by the VPU to the conventional raster-scan order needed by the IPU.
VPU	Video Processing Unit	Multimedia Peripherals	A high-performing video processing unit (VPU), which covers many SD-level and HD-level video decoders and SD-level encoders as a multi-standard video codec engine as well as several important video processing, such as rotation and mirroring. See the i.MX 6Dual/6Quad reference manual (IMX6DQRM) for complete list of VPU’s decoding/encoding capabilities.
WDOG-1	Watchdog	Timer Peripherals	The Watchdog Timer supports two comparison points during each counting period. Each of the comparison points is configurable to evoke an interrupt to the ARM core, and a second point evokes an external event on the WDOG line.

Table 8. Maximum Supply Currents

Power Supply	Conditions	Maximum Current		Unit
		Power Virus	CoreMark	
i.MX 6Quad: VDD_ARM_IN + VDD_ARM23_IN	• ARM frequency = 996 MHz • ARM LDOs set to 1.3V • T_j = 125°C	3920	2500	mA
	• ARM frequency = 852 MHz • ARM LDOs set to 1.3V • T_j = 125°C	3630	2260	mA
i.MX 6Dual: VDD_ARM_IN	• ARM frequency = 996 MHz • ARM LDOs set to 1.3V • T_j = 125°C	2350	1500	mA
	• ARM frequency = 852 MHz • ARM LDOs set to 1.3V • T_j = 125°C	2110	1360	mA
i.MX 6Dual: or i.MX 6Quad: VDD_SOC_IN	• Running 3DMark • GPU frequency = 600 MHz • SOC LDO set to 1.3V • T_j = 125°C	2500		mA
VDD_HIGH_IN	—	125[1]		mA
VDD_SNVS_IN	—	275[2]		µA
USB_OTG_VBUS/ USB_H1_VBUS (LDO 3P0)	—	25[3]		mA
Primary Interface (IO) Supplies				
NVCC_DRAM	—	(see note[4])		
NVCC_ENET	N=10	Use maximum IO equation[5]		
NVCC_LCD	N=29	Use maximum IO equation[5]		
NVCC_GPIO	N=24	Use maximum IO equation[5]		
NVCC_CSI	N=20	Use maximum IO equation[5]		
NVCC_EIM0	N=19	Use maximum IO equation[5]		
NVCC_EIM1	N=14	Use maximum IO equation[5]		
NVCC_EIM2	N=20	Use maximum IO equation[5]		
NVCC_JTAG	N=6	Use maximum IO equation[5]		
NVCC_RGMII	N=6	Use maximum IO equation[5]		
NVCC_SD1	N=6	Use maximum IO equation[5]		
NVCC_SD2	N=6	Use maximum IO equation[5]		
NVCC_SD3	N=11	Use maximum IO equation[5]		
NVCC_NANDF	N=26	Use maximum IO equation[5]		
NVCC_MIPI	—	25.5		mA

Table 8. Maximum Supply Currents (continued)

Power Supply	Conditions	Maximum Current		Unit
		Power Virus	CoreMark	
NVCC_LVDS2P5	—	NVCC_LVDS2P5 is connected to VDD_HIGH_CAP at the board level. VDD_HIGH_CAP is capable of handing the current required by NVCC_LVDS2P5.		
MISC				
DRAM_VREF	—	1		mA

1 The actual maximum current drawn from VDD_HIGH_IN will be as shown plus any additional current drawn from the VDD_HIGH_CAP outputs, depending upon actual application configuration (for example, NVCC_LVDS_2P5, NVCC_MIPI, or HDMI, PCIe, and SATA VPH supplies).

2 Under normal operating conditions, the maximum current on VDD_SNVS_IN is shown Table 8. The maximum VDD_SNVS_IN current may be higher depending on specific operating configurations, such as BOOT_MODE[1:0] not equal to 00, or use of the Tamper feature. During initial power on, VDD_SNVS_IN can draw up to 1 mA if the supply is capable of sourcing that current. If less than 1 mA is available, the VDD_SNVS_CAP charge time will increase.

3 This is the maximum current per active USB physical interface.

4 The DRAM power consumption is dependent on several factors such as external signal termination. DRAM power calculators are typically available from memory vendors which take into account factors such as signal termination.
See the *i.MX 6Dual/6Quad Power Consumption Measurement Application Note* (AN4509) for examples of DRAM power consumption during specific use case scenarios.

5 General equation for estimated, maximum power consumption of an IO power supply:
Imax = N x C x V x (0.5 x F)
Where:
N—Number of IO pins supplied by the power line
C—Equivalent external capacitive load
V—IO voltage
(0.5 xF)—Data change rate. Up to 0.5 of the clock rate (F)
In this equation, Imax is in Amps, C in Farads, V in Volts, and F in Hertz.

4.1.6 Low Power Mode Supply Currents

Table 9 shows the current core consumption (not including I/O) of the i.MX 6Dual/6Quad processors in selected low power modes.

Table 9. Stop Mode Current and Power Consumption

Mode	Test Conditions	Supply	Typical[1]	Unit
WAIT	• ARM, SoC, and PU LDOs are set to 1.225 V • HIGH LDO set to 2.5 V • Clocks are gated • DDR is in self refresh • PLLs are active in bypass (24 MHz) • Supply voltages remain ON	VDD_ARM_IN (1.4 V)	6	mA
		VDD_SOC_IN (1.4 V)	23	mA
		VDD_HIGH_IN (3.0 V)	3.7	mA
		Total	52	mW

- When the PCIE interface is not used, the PCIE_VP, PCIE_VPH, and PCIE_VPTX supplies should be grounded. The input and output supplies for rest of the ports (PCIE_REXT, PCIE_RX_N, PCIE_RX_P, PCIE_TX_N, and PCIE_TX_P) can remain unconnected. It is recommended not to turn the PCIE_VPH supply OFF while the PCIE_VP supply is ON, as it may lead to excessive power consumption. If boundary scan test is used, PCIE_VP, PCIE_VPH, and PCIE_VPTX must remain powered.

4.3 Integrated LDO Voltage Regulator Parameters

Various internal supplies can be powered ON from internal LDO voltage regulators. All the supply pins named *_CAP must be connected to external capacitors. The onboard LDOs are intended for internal use only and should not be used to power any external circuitry. See the i.MX 6Dual/6Quad reference manual (IMX6DQRM) for details on the power tree scheme recommended operation.

NOTE

The *_CAP signals should not be powered externally. These signals are intended for internal LDO or LDO bypass operation only.

4.3.1 Digital Regulators (LDO_ARM, LDO_PU, LDO_SOC)

There are three digital LDO regulators (“Digital”, because of the logic loads that they drive, not because of their construction). The advantages of the regulators are to reduce the input supply variation because of their input supply ripple rejection and their on die trimming. This translates into more voltage for the die producing higher operating frequencies. These regulators have three basic modes.

- Bypass. The regulation FET is switched fully on passing the external voltage, DCDC_LOW, to the load unaltered. The analog part of the regulator is powered down in this state, removing any loss other than the IR drop through the power grid and FET.
- Power Gate. The regulation FET is switched fully off limiting the current draw from the supply. The analog part of the regulator is powered down here limiting the power consumption.
- Analog regulation mode. The regulation FET is controlled such that the output voltage of the regulator equals the programmed target voltage. The target voltage is fully programmable in 25 mV steps.

Optionally LDO_SOC/VDD_SOC_CAP can be used to power the HDMI, PCIe, and SATA PHY's through external connections.

For additional information, see the i.MX 6Dual/6Quad reference manual (IMX6DQRM).

4.3.2 Regulators for Analog Modules

4.3.2.1 LDO_1P1 / NVCC_PLL_OUT

The LDO_1P1 regulator implements a programmable linear-regulator function from VDD_HIGH_IN (see Table 6 for minimum and maximum input requirements). Typical Programming Operating Range is 1.0 V to 1.2 V with the nominal default setting as 1.1 V. The LDO_1P1 supplies the 24 MHz oscillator, PLLs, and USB PHY. A programmable brown-out detector is included in the regulator that can be used by the

Figure 14 to Figure 17 provide few examples of basic EIM accesses to external memory devices with the timing parameters mentioned previously for specific control parameters settings.

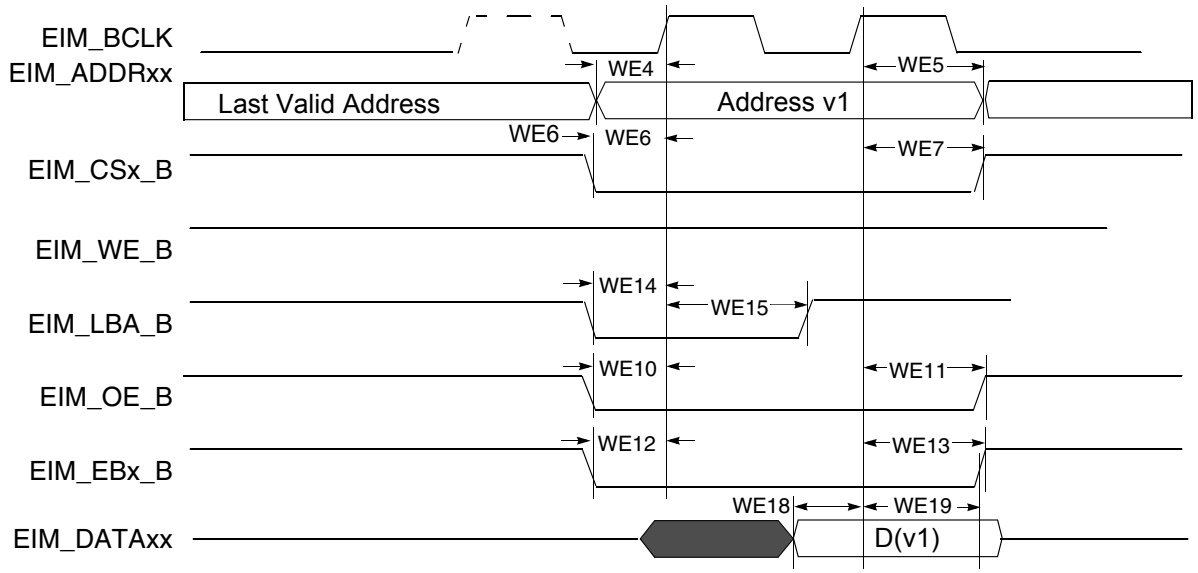


Figure 14. Synchronous Memory Read Access, WSC=1

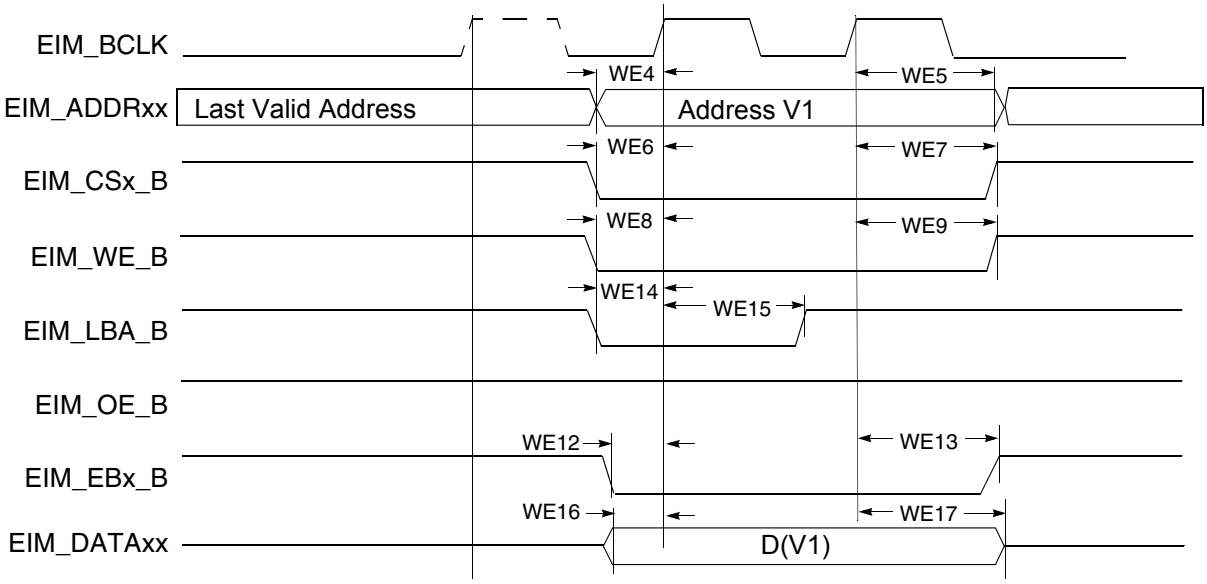
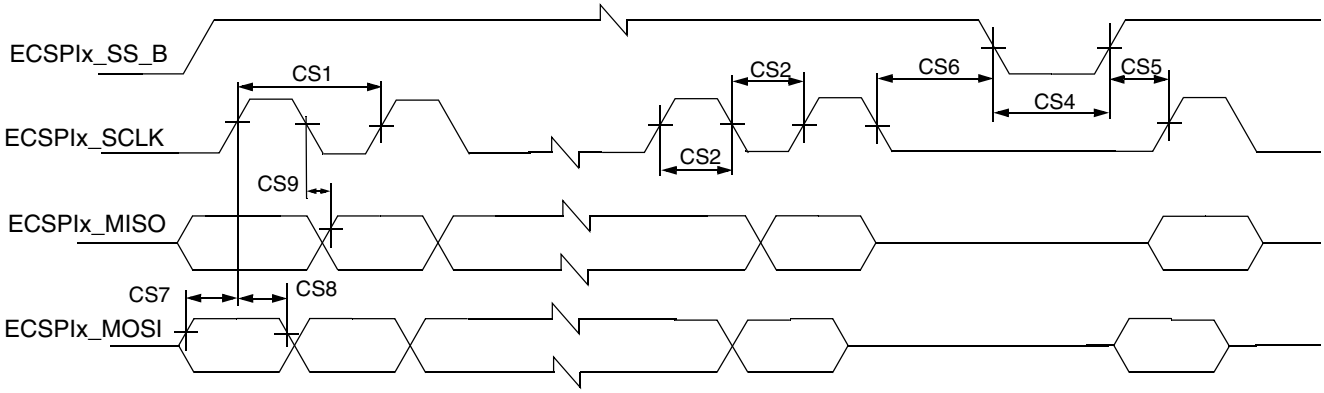


Figure 15. Synchronous Memory, Write Access, WSC=1, WBEA=0 and WADVN=0

4.12.2.2 ECSPI Slave Mode Timing

Figure 36 depicts the timing of ECSPI in slave mode and Table 48 lists the ECSPI slave mode timing characteristics.



Note: ECSPIx_MISO is always driven (not tri-stated) between actual data transmissions. This limits the ECSPI to be connected between a single master and a single slave.

Figure 36. ECSPI Slave Mode Timing Diagram

Table 48. ECSPI Slave Mode Timing Parameters

ID	Parameter	Symbol	Min	Max	Unit
CS1	ECSPIx_SCLK Cycle Time–Read • Slow group[1] • Fast group[2] ECSPIx_SCLK Cycle Time–Write	t_{clk}	 55 40 15	—	ns
CS2	ECSPIx_SCLK High or Low Time–Read • Slow group[1] • Fast group[2] ECSPIx_SCLK High or Low Time–Write	t_{SW}	 26 20 7	—	ns
CS4	ECSPIx_SSx pulse width	t_{CSLH}	Half ECSPIx_SCLK period	—	ns
CS5	ECSPIx_SSx Lead Time (CS setup time)	t_{SCS}	5	—	ns
CS6	ECSPIx_SSx Lag Time (CS hold time)	t_{HCS}	5	—	ns
CS7	ECSPIx_MOSI Setup Time	t_{Smosi}	4	—	ns
CS8	ECSPIx_MOSI Hold Time	t_{Hmosi}	4	—	ns
CS9	ECSPIx_MISO Propagation Delay (C_{LOAD} = 20 pF) • Slow group[1] • Fast group[2]	t_{PDmiso}	4	 25 17	ns

[1] ECSPI slow includes:
ECSPI1/DISP0_DAT22, ECSPI1/KEY_COL1, ECSPI1/CSI0_DAT6, ECSPI2/EIM_OE, ECSPI2/DISP0_DAT17, ECSPI2/CSI0_DAT10, ECSPI3/DISP0_DAT2

[2] ECSPI fast includes:
ECSPI1/EIM_D17, ECSPI4/EIM_D22, ECSPI5/SD2_DAT0, ECSPI5/SD1_DAT0

Table 49. Enhanced Serial Audio Interface (ESAI) Timing (continued)

ID	Parameter[1,2]	Symbol	Expression[2]	Min	Max	Condition[3]	Unit
81	ESAI_TX_CLK rising edge to ESAI_TX_FS out (wr) low[5]	— —	— —	— —	22.0 12.0	x ck i ck	ns
82	ESAI_TX_CLK rising edge to ESAI_TX_FS out (wl) high	— —	— —	— —	19.0 9.0	x ck i ck	ns
83	ESAI_TX_CLK rising edge to ESAI_TX_FS out (wl) low	— —	— —	— —	20.0 10.0	x ck i ck	ns
84	ESAI_TX_CLK rising edge to data out enable from high impedance	— —	— —	— —	22.0 17.0	x ck i ck	ns
86	ESAI_TX_CLK rising edge to data out valid	— —	— —	— —	19.0 13.0	x ck i ck	ns
87	ESAI_TX_CLK rising edge to data out high impedance [67]	— —	— —	— —	21.0 16.0	x ck i ck	ns
89	ESAI_TX_FS input (bl, wr) setup time before ESAI_TX_CLK falling edge[5]	— —	— —	2.0 18.0	— —	x ck i ck	ns
90	ESAI_TX_FS input (wl) setup time before ESAI_TX_CLK falling edge	— —	— —	2.0 18.0	— —	x ck i ck	ns
91	ESAI_TX_FS input hold time after ESAI_TX_CLK falling edge	— —	— —	4.0 5.0	— —	x ck i ck	ns
95	ESAI_RX_HF_CLK/ESAI_TX_HF_CLK clock cycle	—	$2 \times T_C$	15	—	—	ns
96	ESAI_TX_HF_CLK input rising edge to ESAI_TX_CLK output	—	—	—	18.0	—	ns
97	ESAI_RX_HF_CLK input rising edge to ESAI_RX_CLK output	—	—	—	18.0	—	ns

1 i ck = internal clock
x ck = external clock
i ck a = internal clock, asynchronous mode
(asynchronous implies that ESAI_TX_CLK and ESAI_RX_CLK are two different clocks)
i ck s = internal clock, synchronous mode
(synchronous implies that ESAI_TX_CLK and ESAI_RX_CLK are the same clock)

2 bl = bit length
wl = word length
wr = word length relative

3 ESAI_TX_CLK(ESAI_TX_CLK pin) = transmit clock
ESAI_RX_CLK(ESAI_RX_CLK pin) = receive clock
ESAI_TX_FS(ESAI_TX_FS pin) = transmit frame sync
ESAI_RX_FS(ESAI_RX_FS pin) = receive frame sync
ESAI_TX_HF_CLK(ESAI_TX_HF_CLK pin) = transmit high frequency clock
ESAI_RX_HF_CLK(ESAI_RX_HF_CLK pin) = receive high frequency clock

4 For the internal clock, the external clock cycle is defined by Icyc and the ESAI control register.

5 The word-relative frame sync signal waveform relative to the clock operates in the same manner as the bit-length frame sync signal waveform, but it spreads from one serial clock before the first bit clock (like the bit length frame sync signal), until the second-to-last bit clock of the first word in the frame.

6 Periodically sampled and not 100% tested.

Table 59. Electrical Characteristics (continued)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
R_T	Termination resistance	—	45	50	55	Ω
TMDS drivers DC specifications						
V_{OFF}	Single-ended standby voltage	RT = 50 Ω For measurement conditions and definitions, see the first two figures above. Compliance point TP1 as defined in the HDMI specification, version 1.3a, section 4.2.4.	avddtmds ± 10 mV			mV
V_{SWING}	Single-ended output swing voltage		400	—	600	mV
V_H	Single-ended output high voltage For definition, see the second figure above.	If attached sink supports TMDSCLK < or = 165 MHz	avddtmds ± 10 mV			mV
		If attached sink supports TMDSCLK > 165 MHz	avddtmds – 200 mV	—	avddtmds + 10 mV	mV
V_L	Single-ended output low voltage For definition, see the second figure above.	If attached sink supports TMDSCLK < or = 165 MHz	avddtmds – 600 mV	—	avddtmds – 400mV	mV
		If attached sink supports TMDSCLK > 165 MHz	avddtmds – 700 mV	—	avddtmds – 400 mV	mV
R_{TERM}	Differential source termination load (inside HDMI 3D Tx PHY) Although the HDMI 3D Tx PHY includes differential source termination, the user-defined value is set for each single line (for illustration, see the third figure above). **Note:** R_{TERM} can also be configured to be open and not present on TMDS channels.	—	50	—	200	Ω
Hot plug detect specifications						
HPD^{VH}	Hot plug detect high range	—	2.0	—	5.3	V
$VHPD_{VL}$	Hot plug detect low range	—	0	—	0.8	V
HPD_Z	Hot plug detect input impedance	—	10	—	—	kΩ
HPD_t	Hot plug detect time delay	—	—	—	100	µs

4.12.8 Switching Characteristics

Table 60 describes switching characteristics for the HDMI 3D Tx PHY. Figure 53 to Figure 57 illustrate various parameters specified in table.

NOTE

All dynamic parameters related to the TMDS line drivers' performance imply the use of assembly guidelines.

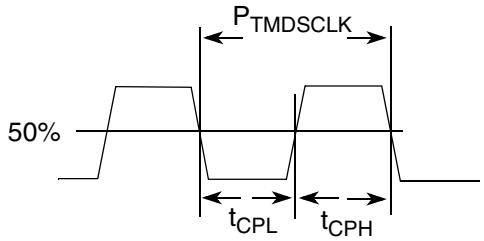


Figure 53. TMDS Clock Signal Definitions

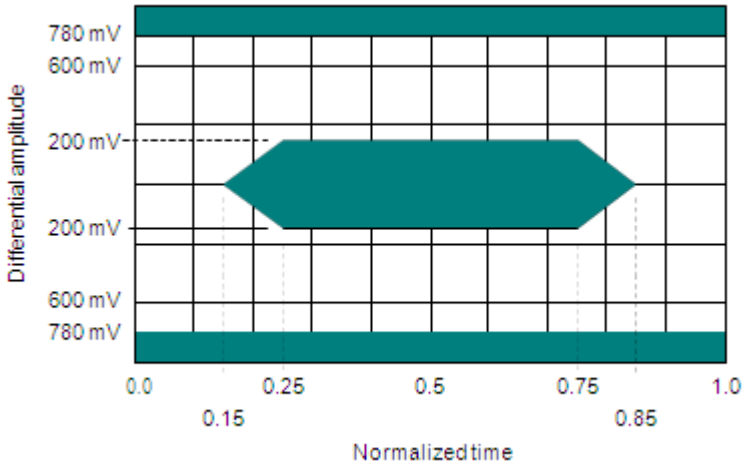


Figure 54. Eye Diagram Mask Definition for HDMI Driver Signal Specification at TP1

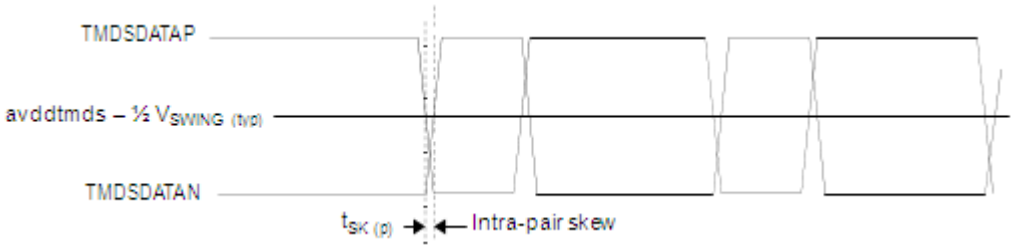


Figure 55. Intra-Pair Skew Definition

4.12.12.9 Low-Power Receiver Timing

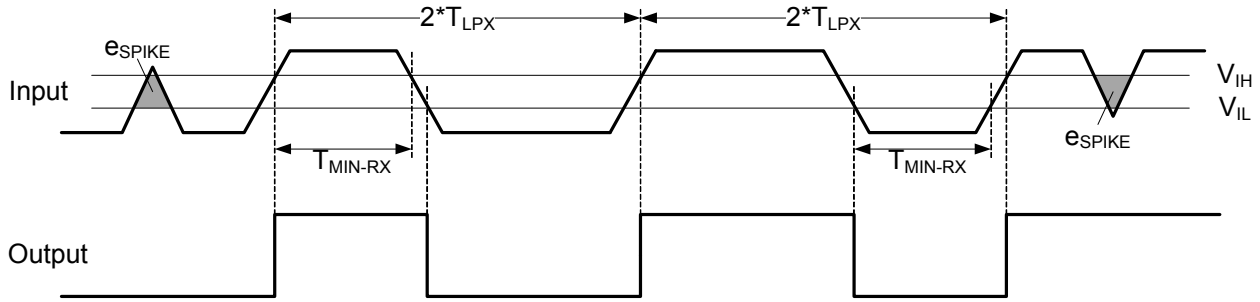


Figure 72. Input Glitch Rejection of Low-Power Receivers

4.12.13 HSI Host Controller Timing Parameters

This section describes the timing parameters of the HSI Host Controller which are compliant with High-Speed Synchronous Serial Interface (HSI) Physical Layer specification version 1.01.

4.12.13.1 Synchronous Data Flow

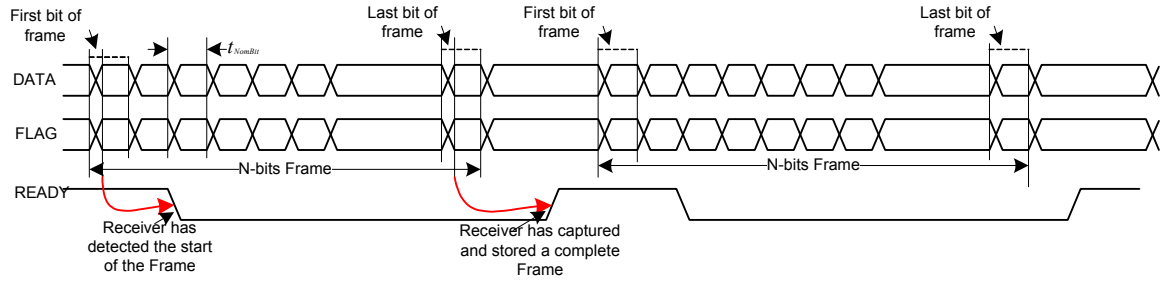


Figure 73. Synchronized Data Flow READY Signal Timing (Frame and Stream Transmission)

4.12.13.2 Pipelined Data Flow

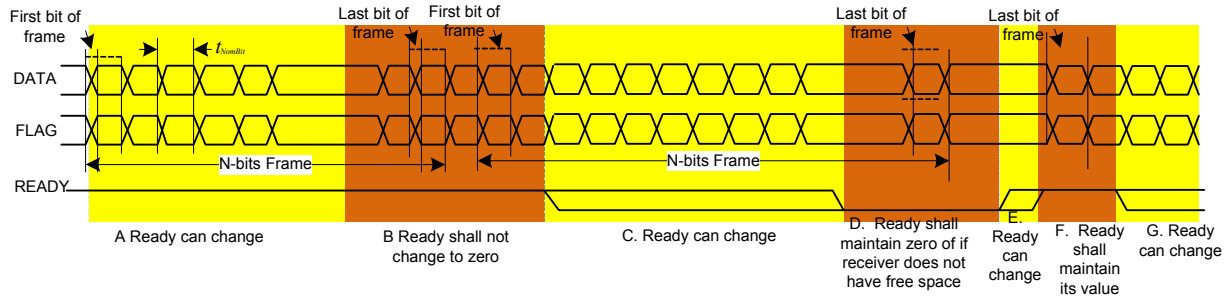


Figure 74. Pipelined Data Flow READY Signal Timing (Frame Transmission Mode)

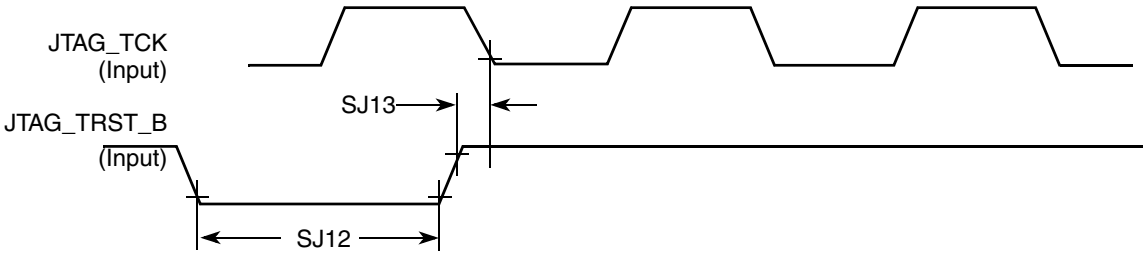


Figure 87. JTAG_TRST_B Timing Diagram

Table 79. JTAG Timing

ID	Parameter[1,2]	All Frequencies		Unit
		Min	Max	
SJ0	JTAG_TCK frequency of operation $1/(3xT_{DC})$[1]	0.001	22	MHz
SJ1	JTAG_TCK cycle time in crystal mode	45	—	ns
SJ2	JTAG_TCK clock pulse width measured at V_M[2]	22.5	—	ns
SJ3	JTAG_TCK rise and fall times	—	3	ns
SJ4	Boundary scan input data set-up time	5	—	ns
SJ5	Boundary scan input data hold time	24	—	ns
SJ6	JTAG_TCK low to output data valid	—	40	ns
SJ7	JTAG_TCK low to output high impedance	—	40	ns
SJ8	JTAG_TMS, JTAG_TDI data set-up time	5	—	ns
SJ9	JTAG_TMS, JTAG_TDI data hold time	25	—	ns
SJ10	JTAG_TCK low to JTAG_TDO data valid	—	44	ns
SJ11	JTAG_TCK low to JTAG_TDO high impedance	—	44	ns
SJ12	JTAG_TRST_B assert time	100	—	ns
SJ13	JTAG_TRST_B set-up time to JTAG_TCK low	40	—	ns

1 T_{DC} = target frequency of SJC
2 V_M = mid-point voltage

4.12.19 SPDIF Timing Parameters

The Sony/Philips Digital Interconnect Format (SPDIF) data is sent using the bi-phase marking code. When encoding, the SPDIF data signal is modulated by a clock that is twice the bit rate of the data signal.

Table 80 and Figure 88 and Figure 89 show SPDIF timing parameters for the Sony/Philips Digital Interconnect Format (SPDIF), including the timing of the modulating Rx clock (SPDIF_SR_CLK) for SPDIF in Rx mode and the timing of the modulating Tx clock (SPDIF_ST_CLK) for SPDIF in Tx mode.

4.12.20 SSI Timing Parameters

This section describes the timing parameters of the SSI module. The connectivity of the serial synchronous interfaces are summarized in Table 81.

Table 81. AUDMUX Port Allocation

Port	Signal Nomenclature	Type and Access
AUDMUX port 1	SSI 1	Internal
AUDMUX port 2	SSI 2	Internal
AUDMUX port 3	AUD3	External – AUD3 I/O
AUDMUX port 4	AUD4	External – EIM or CSPI1 I/O through IOMUXC
AUDMUX port 5	AUD5	External – EIM or SD1 I/O through IOMUXC
AUDMUX port 6	AUD6	External – EIM or DISP2 through IOMUXC
AUDMUX port 7	SSI 3	Internal

NOTE

The terms WL and BL used in the timing diagrams and tables refer to Word Length (WL) and Bit Length (BL).

4.12.20.1 SSI Transmitter Timing with Internal Clock

Figure 90 depicts the SSI transmitter internal clock timing and Table 82 lists the timing parameters for the SSI transmitter internal clock.

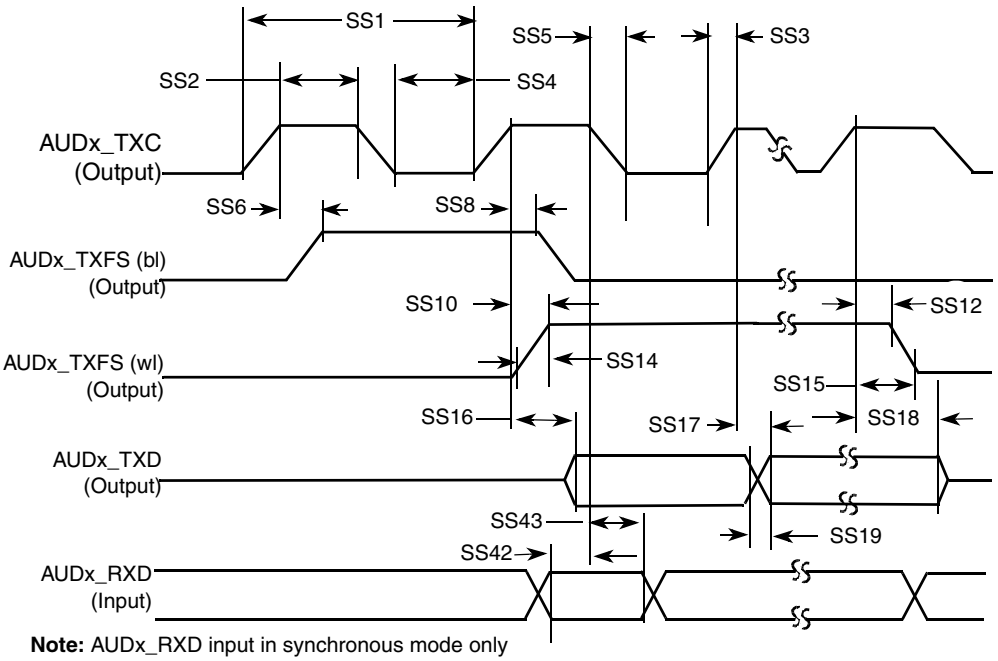


Figure 90. SSI Transmitter Internal Clock Timing Diagram

Table 95. 21 x 21 mm Supplies Contact Assignment (continued)

Supply Rail Name	Ball(s) Position(s)	Remark
VDDHIGH_CAP	H10, J10	Secondary supply for the 2.5 V domain (internal regulator output—requires capacitor if internal regulator is used)
VDDHIGH_IN	H9, J9	Primary supply for the 2.5 V regulator
VDDPU_CAP	H17, J17, K17, L17, M17, N17, P17	Secondary supply for the VPU and GPU (internal regulator output—requires capacitor if internal regulator is used)
VDDSOC_CAP	R10, T10, T13, T14, U10, U13, U14	Secondary supply for the SoC and PU (internal regulator output—requires capacitor if internal regulator is used)
VDDSOC_IN	H16, J16, K16, L16, M16, N16, P16, R16, T16, U16	Primary supply for the SoC and PU regulators
VDDUSB_CAP	F9	Secondary supply for the 3 V domain (internal regulator output—requires capacitor if internal regulator is used)
ZQPAD	AE17	Connect ZQPAD to an external 240Ω 1% resistor to GND. This is a reference used during DRAM output buffer driver calibration.

6.2.3 21 x 21 mm Functional Contact Assignments

Table 96 displays an alpha-sorted list of the signal assignments including power rails. The table also includes out of reset pad state.

Table 96. 21 x 21 mm Functional Contact Assignments

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition[1]			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value[2]
BOOT_MODE0	C12	VDD_SNVS_IN	GPIO	ALT0	SRC_BOOT_MODE0	Input	PD (100K)
BOOT_MODE1	F12	VDD_SNVS_IN	GPIO	ALT0	SRC_BOOT_MODE1	Input	PD (100K)
CLK1_N	C7	VDD_HIGH_CAP	—	—	CLK1_N	—	—
CLK1_P	D7	VDD_HIGH_CAP	—	—	CLK1_P	—	—
CLK2_N	C5	VDD_HIGH_CAP	—	—	CLK2_N	—	—
CLK2_P	D5	VDD_HIGH_CAP	—	—	CLK2_P	—	—
CSI_CLK0M	F4	NVCC_MIPI	—	—	CSI_CLK_N	—	—
CSI_CLK0P	F3	NVCC_MIPI	—	—	CSI_CLK_P	—	—
CSI_D0M	E4	NVCC_MIPI	—	—	CSI_DATA0_N	—	—
CSI_D0P	E3	NVCC_MIPI	—	—	CSI_DATA0_P	—	—
CSI_D1M	D1	NVCC_MIPI	—	—	CSI_DATA1_N	—	—

Table 96. 21 x 21 mm Functional Contact Assignments (continued)

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition[1]			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value[2]
DRAM_DQM7	Y21	NVCC_DRAM	DDR	ALT0	DRAM_DQM7	Output	0
DRAM_RAS	AB15	NVCC_DRAM	DDR	ALT0	DRAM_RAS_B	Output	0
DRAM_RESET	Y6	NVCC_DRAM	DDR	ALT0	DRAM_RESET	Output	0
DRAM_SDBA0	AC15	NVCC_DRAM	DDR	ALT0	DRAM_SDBA0	Output	0
DRAM_SDBA1	Y15	NVCC_DRAM	DDR	ALT0	DRAM_SDBA1	Output	0
DRAM_SDBA2	AB12	NVCC_DRAM	DDR	ALT0	DRAM_SDBA2	Output	0
DRAM_SDCKE0	Y11	NVCC_DRAM	DDR	ALT0	DRAM_SDCKE0	Output	0
DRAM_SDCKE1	AA11	NVCC_DRAM	DDR	ALT0	DRAM_SDCKE1	Output	0
DRAM_SDCLK_0	AD15	NVCC_DRAM	DDRCLK	ALT0	DRAM_SDCLK0_P	Output	0
DRAM_SDCLK_0_B	AE15	NVCC_DRAM	DDRCLK	—	DRAM_SDCLK0_N	—	—
DRAM_SDCLK_1	AD14	NVCC_DRAM	DDRCLK	ALT0	DRAM_SDCLK1_P	Output	0
DRAM_SDCLK_1_B	AE14	NVCC_DRAM	DDRCLK	—	DRAM_SDCLK1_N	—	—
DRAM_SDODT0	AC16	NVCC_DRAM	DDR	ALT0	DRAM_ODT0	Output	0
DRAM_SDODT1	AB17	NVCC_DRAM	DDR	ALT0	DRAM_ODT1	Output	0
DRAM_SDQS0	AE3	NVCC_DRAM	DDRCLK	ALT0	DRAM_SDQS0_P	Input	Hi-Z
DRAM_SDQS0_B	AD3	NVCC_DRAM	DDRCLK	—	DRAM_SDQS0_N	—	—
DRAM_SDQS1	AD6	NVCC_DRAM	DDRCLK	ALT0	DRAM_SDQS1_P	Input	Hi-Z
DRAM_SDQS1_B	AE6	NVCC_DRAM	DDRCLK	—	DRAM_SDQS1_N	—	—
DRAM_SDQS2	AD8	NVCC_DRAM	DDRCLK	ALT0	DRAM_SDQS2_P	Input	Hi-Z
DRAM_SDQS2_B	AE8	NVCC_DRAM	DDRCLK	—	DRAM_SDQS2_N	—	—
DRAM_SDQS3	AC10	NVCC_DRAM	DDRCLK	ALT0	DRAM_SDQS3_P	Input	Hi-Z
DRAM_SDQS3_B	AB10	NVCC_DRAM	DDRCLK	—	DRAM_SDQS3_N	—	—
DRAM_SDQS4	AD18	NVCC_DRAM	DDRCLK	ALT0	DRAM_SDQS4_P	Input	Hi-Z
DRAM_SDQS4_B	AE18	NVCC_DRAM	DDRCLK	—	DRAM_SDQS4_N	—	—
DRAM_SDQS5	AD20	NVCC_DRAM	DDRCLK	ALT0	DRAM_SDQS5_P	Input	Hi-Z
DRAM_SDQS5_B	AE20	NVCC_DRAM	DDRCLK	—	DRAM_SDQS5_N	—	—
DRAM_SDQS6	AD23	NVCC_DRAM	DDRCLK	ALT0	DRAM_SDQS6_P	Input	Hi-Z
DRAM_SDQS6_B	AE23	NVCC_DRAM	DDRCLK	—	DRAM_SDQS6_N	—	—
DRAM_SDQS7	AA25	NVCC_DRAM	DDRCLK	ALT0	DRAM_SDQS7_P	Input	Hi-Z
DRAM_SDQS7_B	AA24	NVCC_DRAM	DDRCLK	—	DRAM_SDQS7_N	—	—
DRAM_SDWE	AB16	NVCC_DRAM	DDR	ALT0	DRAM_SDWE_B	Output	0
DSI_CLK0M	H3	NVCC_MIPI	—	—	DSI_CLK_N	—	—
DSI_CLK0P	H4	NVCC_MIPI	—	—	DSI_CLK_P	—	—
DSI_D0M	G2	NVCC_MIPI	—	—	DSI_DATA0_N	—	—
DSI_D0P	G1	NVCC_MIPI	—	—	DSI_DATA0_P	—	—
DSI_D1M	H2	NVCC_MIPI	—	—	DSI_DATA1_N	—	—

Table 96. 21 x 21 mm Functional Contact Assignments (continued)

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition[1]			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value[2]
GPIO_4	R6	NVCC_GPIO	GPIO	ALT5	GPIO1_IO04	Input	PU (100K)
GPIO_5	R4	NVCC_GPIO	GPIO	ALT5	GPIO1_IO05	Input	PU (100K)
GPIO_6	T3	NVCC_GPIO	GPIO	ALT5	GPIO1_IO06	Input	PU (100K)
GPIO_7	R3	NVCC_GPIO	GPIO	ALT5	GPIO1_IO07	Input	PU (100K)
GPIO_8	R5	NVCC_GPIO	GPIO	ALT5	GPIO1_IO08	Input	PU (100K)
GPIO_9	T2	NVCC_GPIO	GPIO	ALT5	GPIO1_IO09	Input	PU (100K)
HDMI_CLKM	J5	HDMI_VPH	—	—	HDMI_TX_CLK_N	—	—
HDMI_CLKP	J6	HDMI_VPH	—	—	HDMI_TX_CLK_P	—	—
HDMI_D0M	K5	HDMI_VPH	—	—	HDMI_TX_DATA0_N	—	—
HDMI_D0P	K6	HDMI_VPH	—	—	HDMI_TX_DATA0_P	—	—
HDMI_D1M	J3	HDMI_VPH	—	—	HDMI_TX_DATA1_N	—	—
HDMI_D1P	J4	HDMI_VPH	—	—	HDMI_TX_DATA1_P	—	—
HDMI_D2M	K3	HDMI_VPH	—	—	HDMI_TX_DATA2_N	—	—
HDMI_D2P	K4	HDMI_VPH	—	—	HDMI_TX_DATA2_P	—	—
HDMI_HPD	K1	HDMI_VPH	—	—	HDMI_TX_HPD	—	—
JTAG_MOD	H6	NVCC_JTAG	GPIO	ALT0	JTAG_MODE	Input	PU (100K)
JTAG_TCK	H5	NVCC_JTAG	GPIO	ALT0	JTAG_TCK	Input	PU (47K)
JTAG_TDI	G5	NVCC_JTAG	GPIO	ALT0	JTAG_TDI	Input	PU (47K)
JTAG_TDO	G6	NVCC_JTAG	GPIO	ALT0	JTAG_TDO	Output	Keeper
JTAG_TMS	C3	NVCC_JTAG	GPIO	ALT0	JTAG_TMS	Input	PU (47K)
JTAG_TRSTB	C2	NVCC_JTAG	GPIO	ALT0	JTAG_TRST_B	Input	PU (47K)
KEY_COL0	W5	NVCC_GPIO	GPIO	ALT5	GPIO4_IO06	Input	PU (100K)
KEY_COL1	U7	NVCC_GPIO	GPIO	ALT5	GPIO4_IO08	Input	PU (100K)
KEY_COL2	W6	NVCC_GPIO	GPIO	ALT5	GPIO4_IO10	Input	PU (100K)
KEY_COL3	U5	NVCC_GPIO	GPIO	ALT5	GPIO4_IO12	Input	PU (100K)
KEY_COL4	T6	NVCC_GPIO	GPIO	ALT5	GPIO4_IO14	Input	PU (100K)
KEY_ROW0	V6	NVCC_GPIO	GPIO	ALT5	GPIO4_IO07	Input	PU (100K)
KEY_ROW1	U6	NVCC_GPIO	GPIO	ALT5	GPIO4_IO09	Input	PU (100K)
KEY_ROW2	W4	NVCC_GPIO	GPIO	ALT5	GPIO4_IO11	Input	PU (100K)
KEY_ROW3	T7	NVCC_GPIO	GPIO	ALT5	GPIO4_IO13	Input	PU (100K)
KEY_ROW4	V5	NVCC_GPIO	GPIO	ALT5	GPIO4_IO15	Input	PD (100K)
LVDS0_CLK_N	V4	NVCC_LVDS_2P5	LVDS	—	LVDS0_CLK_N	—	—
LVDS0_CLK_P	V3	NVCC_LVDS_2P5	LVDS	ALT0	LVDS0_CLK_P	Input	Keeper
LVDS0_TX0_N	U2	NVCC_LVDS_2P5	LVDS	—	LVDS0_TX0_N	—	—
LVDS0_TX0_P	U1	NVCC_LVDS_2P5	LVDS	ALT0	LVDS0_TX0_P	Input	Keeper
LVDS0_TX1_N	U4	NVCC_LVDS_2P5	LVDS	—	LVDS0_TX1_N	—	—

[2] Variance of the pull-up and pull-down strengths are shown in the tables as follows:
- Table 22, “GPIO I/O DC Parameters,” on page 40.
- Table 24, “LPDDR2 I/O DC Electrical Parameters,” on page 42.
- Table 25, “DDR3/DDR3L I/O DC Electrical Parameters,” on page 42.

[3] ENET_REF_CLK is used as a clock source for MII and RGMII modes only. RMII mode uses either GPIO_16 or RGMII_TX_CTL as a clock source. For more information on these clocks, see your specific device reference manual and the *Hardware Development Guide for i.MX 6Quad, 6Dual, 6DualLite, 6Solo Families of Applications Processors* (IMX6DQ6SDLHDG).

6.2.4 Signals with Different Reset States

For most of the signals, the state during reset is same as the state after reset, given in Out of Reset Condition column of Table 96, “21 x 21 mm Functional Contact Assignments”. However, there are few signals for which the state during reset is different from the state after reset. These signals along with their state during reset are given in Table 97.

Table 97. Signals with Differing Before Reset and After Reset States

Ball Name	Before Reset State	
	Input/Output	Value
EIM_A16	Input	PD (100K)
EIM_A17	Input	PD (100K)
EIM_A18	Input	PD (100K)
EIM_A19	Input	PD (100K)
EIM_A20	Input	PD (100K)
EIM_A21	Input	PD (100K)
EIM_A22	Input	PD (100K)
EIM_A23	Input	PD (100K)
EIM_A24	Input	PD (100K)
EIM_A25	Input	PD (100K)
EIM_DA0	Input	PD (100K)
EIM_DA1	Input	PD (100K)
EIM_DA2	Input	PD (100K)
EIM_DA3	Input	PD (100K)
EIM_DA4	Input	PD (100K)
EIM_DA5	Input	PD (100K)
EIM_DA6	Input	PD (100K)
EIM_DA7	Input	PD (100K)
EIM_DA8	Input	PD (100K)
EIM_DA9	Input	PD (100K)
EIM_DA10	Input	PD (100K)
EIM_DA11	Input	PD (100K)
EIM_DA12	Input	PD (100K)
EIM_DA13	Input	PD (100K)

7 Revision History

Table 99 provides a revision history for the i.MX 6Dual/6Quad data sheet.

Table 99. i.MX 6Dual/6Quad Data Sheet Document Revision History

Rev. Number	Date	Substantive Change(s)
5	09/2017	Rev. 5 changes include the following: • Changed throughout: – Changed terminology from “floating” to “not connected”. – Removed VADC feature from 19mm x 19mm package. Contact NXP sales and marketing with enablement options. • Section 1, “Introduction” on page 1: Corrected typo in last sentence of first paragraph “aut1omotive”. • Section 1.2, “Features” on page 5: Changed Internal/external peripheral item from “LVDS serial ports—One port up to 165 MPixels/sec…” to: “…—One port up to 170 MPixels/sec…”. • Table 1, “Example Orderable Part Numbers”: Added part numbers for silicon revision 1.4 with suffix “E”. • Section 1.3, “Signal Naming Convention” on page 8” and Section 6.1, “Signal Naming Convention”: changed wording from *updated* or *changed signal naming,* to *standard signal naming*. • Table 2, “i.MX 6Dual/6Quad Modules List,” on page 11: – Added bullet to uSDHC row: “Conforms to the SD Host Controller Standard Specification v3.0” • Section 4, “Electrical Characteristics” on page 20: Changed several references from JESD and JEDEC standards to cross references to the Section 4.10, “Multi-Mode DDR Controller (MMDC). • Table 4, “Absolute Maximum Ratings,” on page 21: Multiple changes: – Core supply voltages: Separated rows by LDO enabled and LDO bypass. For LDO enabled, changed maximum value from 1.5 to 1.6V. – Renamed Internal supply voltages to Core supply output voltage (LDO enabled) and changed maximum value from 1.3 to 1.4V. Added symbol NVCC_PLL_OUT. – Reordered VDD_HIGH_IN row and changed maximum value from 3.6 to 3.7V. – DDR I/O supply voltage row changes: — Changed Symbols from “Supplies denoted as I/O supply” to: “NVCC_DRAM” — Added footnote. – GPIO I/O supply voltage: Added symbols. Changed maximum value from 3.6 to 3.7V. – Resequenced: HDMI, PCIe, and SATA PHY high (VPH) supply voltage to precede low (VP) – Added row: RGMII I/O supply voltage – Added row, V_{in}/V_{out} input/output voltage range (non-DDR pins) distinguishing between DDR pins. – Changed maximum value for V_{in}/V_{out} input/output voltage range DDR pins to OVDD+0.4. – Added footnotes to both maximum values of V_{in}/V_{out} input/output voltage range. – Added row: USB_OTG_CHD_B • Section 4.1.2, “Thermal Resistance” on page 22: Added NOTE: “Per JEDEC JESD51-2, the intent of thermal resistance measurements…”. • Section 4.1.5, “Maximum Measured Supply Currents” on page 26: Clarified language throughout this section regarding the use case to estimate the maximum supply current. • Section 4.2.1, “Power-Up Sequence” on page 33: – Removed content about calculating the proper current limiting resistor for a coin cell. – Removed inference to internal POR. • Section 4.5.2, “OSC32K” on page 37: Removed content about calculating the proper current limiting resistor for a coin cell. • Section 4.6.1, “XTALI and RTC_XTALI (Clock Inputs) DC Parameters” on page 39: – Added “NOTE: The Vil and Vih specifications only apply when an external clock source is used…”. *(Revision History table continues on next page.)*

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